DR. GOZDE TUTUNCUOGLU

CONTACT Assistant Professor 586-464-7330 INFORMATION Electrical and Computer Engineering gozde@wayne.edu

Wayne State University Google Scholar Page (h-index: 29, citations: 2108)

Faculty Profile Research Group Page

DOMAIN Novel Materials and Devices for Non von Neumann Computing

INTERESTS Quantum and Neuromorphic Computing

Data-driven Materials Discovery and Experimental Design

PROFESSIONAL Wayne State University, Detroit, MI

EXPERIENCE Assistant Professor of Electrical and Computer Engineering

t Professor of Electrical and Computer Engineering April 2021 - Present

Director of ECE Online Masters Program: Semiconductor Engineering September 2023 - Present

Microsoft Quantum Lab, Delft, Netherlands

Researcher October 2019 - February 2021

Project: Robust and scalable technologies to develop topological qubits: Low-temperature epitaxial super-

conductor growth for in-situ fabricated quantum devices

Georgia Institute of Technology, Atlanta, GA

Postdoctoral Researcher

February 2017 - September 2019

Project: Electronic Devices via Bottom-up Co-axial Nanolithography: Towards Large Scale Fabrication of

Si Nanowire Transistors with Prof. Michael A. Filler and Prof.Eric Vogel

EDUCATION Ecole Polytechnique Federale de Lausanne (EPFL), Lausanne, Switzerland

Ph.D., Materials Science and Engineering

2012-2016

Thesis Title: Optoelectronic Properties of III-V Nanostructures Grown by Molecular Beam Epitaxy

Advisor: Prof. Anna Fontcuberta i Morral

M.S., Materials Science and Engineering

2010-2012

Thesis Title: Doping and Characterization of GaAs Nanowires with Sulphur Monolayer Doping

Advisor: Prof. Anna Fontcuberta i Morral

Sabanci University, Istanbul, Turkey

B.S., *Materials Science and Engineering*, Minor: Physics

2006-2010

Highest Honors

RESEARCH SUPPORT **NSF** - Division of Computing and Communication Foundations

04/15/2022 - 03/31/2024

CRII: 3D Printed Application-Specific Neuromorphic Circuits: Design, Fabrication, and Implementation

Award Number: 2153177

Role: **Single PI** Budget: \$174,889

NSF - Division Of Electrical, Communication & Cyber Systems

09/01/2023 - 08/31/2028

RCN:SC: MSN Force: A Midwest Semiconductor Collaborative Network for Work Force Training Award

Number: 2332207 Role: **Lead PI** Budget: \$766,136

Michigan Economic Development Corporation

01/01/2024 - 01/01/2025

IndustryCraft: Industry-Aligned Certificate Programs in Semiconductor Engineering Cayuse Number: 23-

1218

Role: Lead PI Budget: \$303,870

Michigan Economic Development Corporation

01/01/2024 - 01/01/2025

IndustryCraft: An Experiential Learning Program for Future Semiconductor Engineers Cayuse Number: 23-

1225

Role: Lead PI Budget: \$275,852

Oak Ridge National Lab User Proposal

08/01/2022 - 07/31/2024

Enhancing Memristor Device Performance through Comprehensive Defect-Engineering

Award Number: CNMS2022-B-01539

Role: Single PI

Budget: Covers yearly equipment and operating costs (Estimated to be \$30-40K in standard cleanroom fees)

Oak Ridge National Lab User Proposal

08/01/2023 - 07/31/2025

Nanoscale 3D Printing for Neuromorphic Circuitry

Award Number: CNMS2023-B-02040

Role: Single PI

Budget: Covers yearly equipment and operating costs (Estimated to be \$30-40K in standard cleanroom fees)

TEACHING SUPPORT

Wayne State College of Engineering 2022 Technology Advisory Committee Proposal

2022-2023

COMSOL Multiphysics - A comprehensive, interdisciplinary finite element simulation tool for engineering design at the Wayne State College of Engineering

Budget: \$14,528

SELECTED

Authored and coauthored 55 journal publications, h-index:29, citations:2108 on semiconductor nanostruc-PUBLICATIONS ture growth and device fabrication for nanoelectronics applications.

A selected list of the five journal articles is provided here:

- [1] The Impact of Operation Conditions on Potentiation, Depression and Endurance Dynamics of Tantalum Oxide RRAMs: Moazzeni, A, Chowdhury, and Tutuncuoglu, G. 2023 IEEE International Integrated Reliability Workshop (IIRW) Just accepted. IEEE.
- [2] Role of Defects in Resistive Switching Dynamics of Memristors: Tutuncuoglu, G.; Mannodi-Kanakkithodi, A. MRS Communications, 12, pp. 531–542 (2022)
- [3] Reducing Conductivity Variability in Si Nanowires via Surface Passivation for Nanoelectronics: W.Yuan, G. Tutuncuoglu et al. ACS Applied Nano Materials, vol. 4, pp. 3852-3860, (2021)
- [4] Bottom-Up Masking of Si/Ge Surfaces and Nanowire Heterostructures via Surface Initiated Polymerization and Selective Etching: Mohabir, A.; Tutuncuoglu, G. et al.; ACS Nano, 14, 282-288, (2020)
- [5] Template Assisted Scalable Nanowire Networks: Friedl, M.; Cerveny, K.; Weigele, P.; Tutuncuoglu, G. et al.; Nano Letters 18, 4, 2666–2671, (2018)

TEACHING & MENTORING

Wayne State University, Detroit, MI

Courses:

EXPERIENCE

ECE 9997 - Doctoral Seminar (Fall 2021)

ECE 5995 - Special Topics on Nanoelectronics (Winter 2022)

ECE 4600 - Capstone Design (Fall 2022)

ECE 5580 - Advanced Nanoelectronics (Winter 2022 - New course)

ECE 7995 - Advanced Semiconductor Manufacturing (Fall 2023 - New course)

Mentored Students:

Md Tawsif Rahman Chowdhury - PhD Student

Alireza Moazzeni - PhD Student

Avinash Dutt - Master Student

Ahmedul Khan - Master Student

Riley Hilton - Summer REU Student 2022

Kieran Vacek - Summer REU Student 2023

EPFL, Lausanne, Switzerland

Master Thesis and Project Co-Supervisor (2012-2016)

Bachelor and Master Project Co-Supervisor (4 Students), Master Thesis Co-Supervisor (3 Students)

Sabanci University, Istanbul, Turkey

Coordinator of Moderator Education Program in Academic Support Program (2008-2010)

Teaching Assistant of Thermodynamics course in Sabanci University, Istanbul, Turkey (Spring 2009)

Calculus and Natural Sciences 101 & 102 Tutor in Academic Support Program (2006-2007)

SERVICE

ECE Search Committee, ECE Outreach Committee Chair

Chair of American Vacuum Society, Michigan Chapter

Chair of IEEE - Southeastern Michigan - Woman in Engineering Affinity

Guest Editor of Nanomaterials - Special Issue on Thermal Transport in Nanoscale

Review Panelist of National Science Foundation: Electrical, Communications and Cyber Systems (ECCS), Electronic, Photonic, and Magnetic Devices (EPMD)

Faculty participant at NSF Research Experiences for Undergraduates: Summer Academy in Sustainable Manufacturing

Reviewer for Nanotechnology, Nanomaterials, Nanoscale, MRS Advances, Biosensors journals

Member of IEEE, Materials Research Society (MRS)

LECTURES A INVITED SEMINARS

- LECTURES AND Invited Seminar at Synopsys Academic Speaker Series, February 2024
 - Invited Seminar at American Vacuum Society Annual Michigan Section Meeting, June, 2023
 - ECE Department Seminar: Defect-engineering as a Route Towards Controlled Ionic-Transport Pathways in Synaptic Devices, hosted by ECE Department, at Michigan State University, USA, April 2022
 - ABC Seminars: Engineering Nanoscale Devices for Novel Computing Paradigms hosted by Physics and Astronomy Department, at Wayne State University, USA, December 2021
 - ECE Department Seminar: Semiconductor Nanostructures and Their Applications in Optoelectronics, Nanoelectronics and Novel Computing Devices, hosted by Wayne State University, ECE Department, USA, July 2020
 - Optoelectronic Properties of III-V Nanostructures Grown by Molecular Beam Epitaxy hosted by Prof. Paul McIntyre, at Stanford University, USA, September 2017

- Phase Engineering of III-V Nanostructures Grown by Molecular Beam Epitaxy hosted by Prof. Harry Atwater, at California Institute of Technology, USA, July 2016
- III-V Nanostructures grown by Molecular Beam Epitaxy and Research at EPFL hosted by Prof. Cleva Ow Yang, at Sabanci University, Istanbul, Turkey, November 2015
- Optical Properties of Nanowires (Raman and PL Spectroscopy) *lecture on behalf of Prof. Anna Fontcuberta i Morral, at Pulse Summer School - Epitaxy Updates and Promises Porquerolles, France, September 2015

- PRESENTATIONS Crystal Phase Prediction of GaAs Nanowires with Machine Learning (Poster) Machine Learning in Science and Engineering 2019, Atlanta, USA
 - Thermal Transport in Si Nanowires with Axially Modulated Diameters MRS Fall 2018, Boston, USA
 - Defect-Free GaAs Nanostructures by Controlling the Orientation MRS Fall 2016, Boston, USA
 - III-V Nanowires, Growth Challenges and Applications in Next Generation Photovoltaics * Invited talk on behalf of Prof. Anna Fontcuberta i Morral CIMTEC 2016 Perugia, Italy, June 2016
 - Quantum Heterostructures Based on GaAs Nanomembranes for Photonic Applications 2016 IEEE Photonics Society Summer Topical Meeting Series Newport Beach, USA
 - III-V Nanowire-Based Heterostructures Grown with MBE NanoTR-10 2014, Istanbul, Turkey

HONORS AND AWARDS

- Georgia Tech Chemical and Biomolecular Engineering Department Postdoc Fellowship (February 2017)
- Selected as the only participant of Turkey in Lindau Nobel Laureate Meetings Lindau, Germany (July 2016)

SUBMITTED AND IN **PREPARATION**

1. Exploring Self-Directed Channel Memristor Device Metrics and Variability: Avinash Dutt, Alireza Moazzeni, Gozde Tutuncuoglu; Submitted to DRC 2024